

N-channel 60 V, 0.0028 Ω typ., 80 A STripFET™ F7 Power MOSFETs in H<sup>2</sup>PAK-2 and H<sup>2</sup>PAK-6 packages

Datasheet - production data

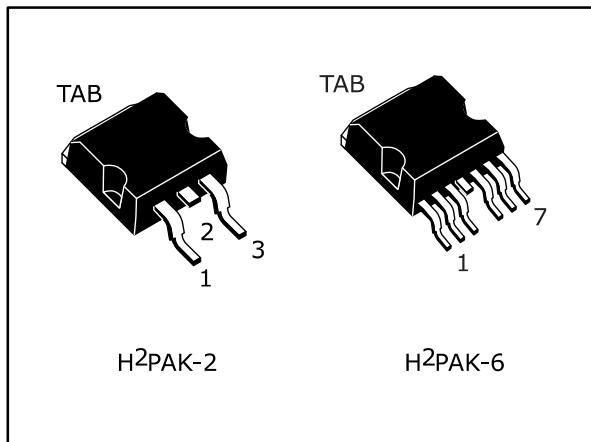
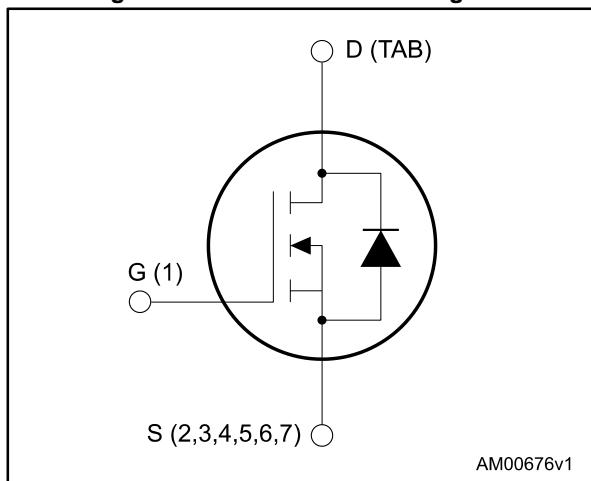


Figure 1: Internal schematic diagram



## Features

Order code	V <sub>DS</sub>	R <sub>DS(on)</sub> max.	I <sub>D</sub>	P <sub>TOT</sub>
STH140N6F7-2	60 V	0.0032 Ω	80 A	158 W
STH140N6F7-6				

- Among the lowest R<sub>DS(on)</sub> on the market
- Excellent figure of merit (FoM)
- Low C<sub>rss</sub>/C<sub>iss</sub> ratio for EMI immunity
- High avalanche ruggedness

## Applications

- Switching applications

## Description

This N-channel Power MOSFET utilizes STripFET™ F7 technology with an enhanced trench gate structure that results in very low on-state resistance, while also reducing internal capacitance and gate charge for faster and more efficient switching.

Table 1: Device summary

Order code	Marking	Package	Packing
STH140N6F7-2	140N6F7	H <sup>2</sup> PAK-2	Tape and Reel
STH140N6F7-6	140N6F7	H <sup>2</sup> PAK-6	Tape and Reel

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# 1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
$V_{DS}$	Drain-source voltage	60	V
$V_{GS}$	Gate-source voltage	$\pm 20$	V
$I_D^{(1)}$	Drain current (continuous) at $T_{case} = 25^\circ\text{C}$	80	A
	Drain current (continuous) at $T_{case} = 100^\circ\text{C}$	80	
$I_{DM}^{(2)}$	Drain current (pulsed)	320	A
$P_{TOT}$	Total dissipation at $T_{case} = 25^\circ\text{C}$	158	W
$T_{stg}$	Storage temperature	-55 to 175	$^\circ\text{C}$
$T_j$	Maximum junction temperature	175	

**Notes:**

(1) Current is limited by package.

(2) Pulse width is limited by safe operating area.

Table 3: Thermal data

Symbol	Parameter	Value	Unit
$R_{thj-pcb}^{(1)}$	Thermal resistance junction-pcb	35	$^\circ\text{C}/\text{W}$
$R_{thj-case}$	Thermal resistance junction-case	0.95	

**Notes:**(1) When mounted on a 1-inch<sup>2</sup> FR-4, 2 oz Cu board.

## 2 Electrical characteristics

( $T_{case} = 25^\circ C$  unless otherwise specified)

**Table 4: Static**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0 V, I_D = 1 mA$	60			V
$I_{DSS}$	Zero gate voltage drain current	$V_{GS} = 0 V, V_{DS} = 60 V$			1	$\mu A$
		$V_{GS} = 0 V, V_{DS} = 60 V, T_{case} = 125^\circ C$			100	
$I_{GSS}$	Gate-body leakage current	$V_{DS} = 0 V, V_{GS} = +20 V$			100	nA
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2		4	V
$R_{DS(on)}$	Static drain-source on-resistance	$V_{GS} = 10 V, I_D = 40 A$		0.0028	0.0032	$\Omega$

**Table 5: Dynamic**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$C_{iss}$	Input capacitance	$V_{DS} = 25 V, f = 1 MHz, V_{GS} = 0 V$	-	3100	-	pF
$C_{oss}$	Output capacitance		-	1520	-	
$C_{rss}$	Reverse transfer capacitance		-	193	-	
$Q_g$	Total gate charge	$V_{DD} = 30 V, I_D = 80 A, V_{GS} = 10 V$ (see <a href="#">Figure 14: "Gate charge test circuit"</a> )	-	55	-	nC
$Q_{gs}$	Gate-source charge		-	19	-	
$Q_{gd}$	Gate-drain charge		-	18	-	

**Table 6: Switching times**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$V_{DD} = 30 V, I_D = 40 A, R_G = 4.7 \Omega, V_{GS} = 10 V$ (see <a href="#">Figure 13: "Switching times test circuit for resistive load"</a> and <a href="#">Figure 18: "Switching time waveform"</a> )	-	24	-	ns
$t_r$	Rise time		-	68	-	
$t_{d(off)}$	Turn-off delay time		-	39	-	
$t_f$	Fall time		-	20	-	

Table 7: Source-drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{SD}^{(1)}$	Forward on voltage	$V_{GS} = 0 \text{ V}$ , $I_{SD} = 80 \text{ A}$	-		1.2	V
$t_{rr}$	Reverse recovery time	$I_{SD} = 80 \text{ A}$ , $dI/dt = 100 \text{ A}/\mu\text{s}$ , $V_{DD} = 48 \text{ V}$ (see <i>Figure 15: "Test circuit for inductive load switching and diode recovery times"</i> )	-	42.4		ns
$Q_{rr}$	Reverse recovery charge		-	38.2		nC
$I_{RRM}$	Reverse recovery current		-	1.8		A

**Notes:**(1) Pulse test: pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5%.

## 2.1

## Electrical characteristics (curves)

Figure 2: Safe operating area

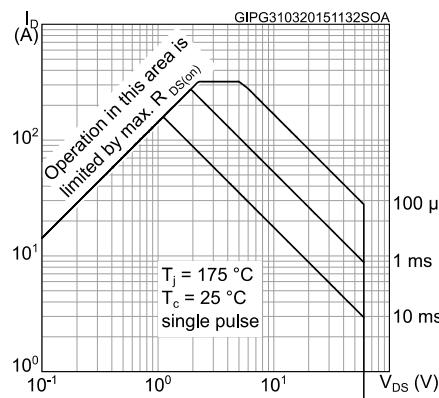


Figure 3: Thermal impedance

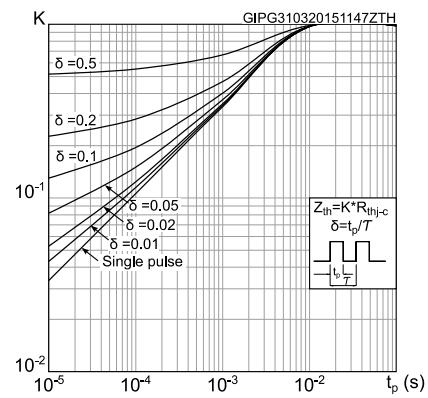


Figure 4: Output characteristics

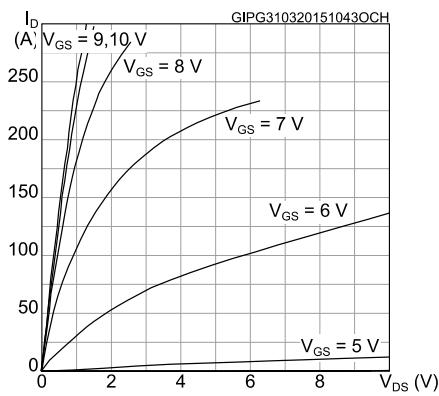


Figure 5: Transfer characteristics

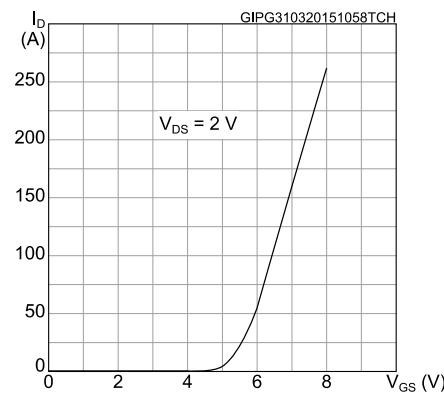


Figure 6: Gate charge vs gate-source voltage

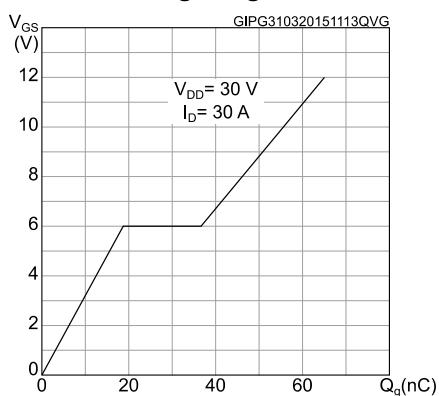
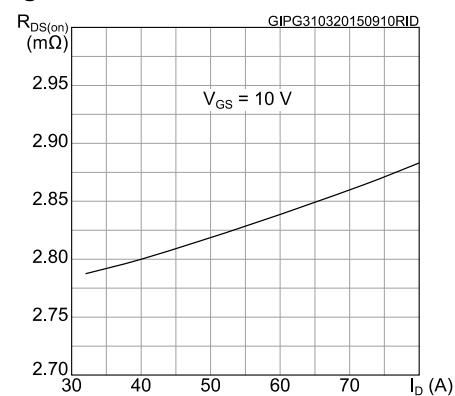
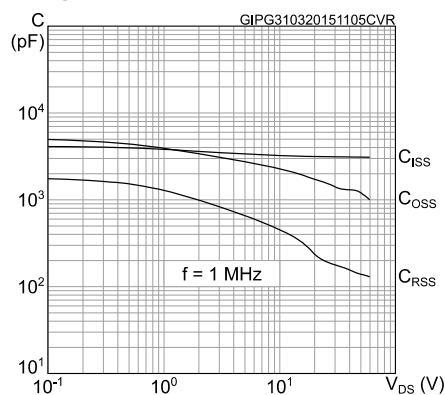
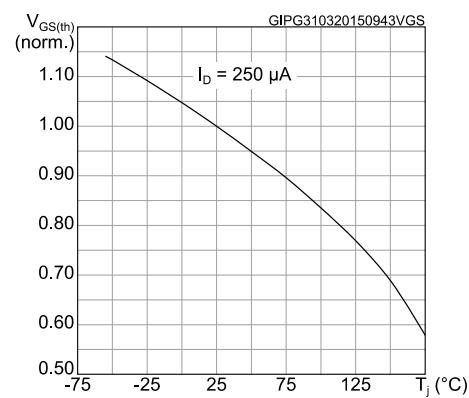
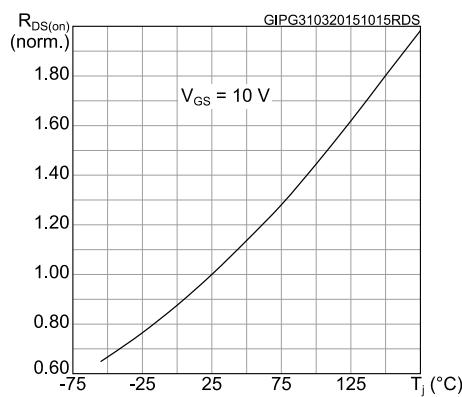
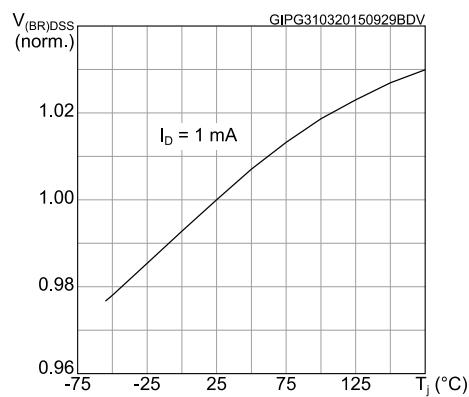
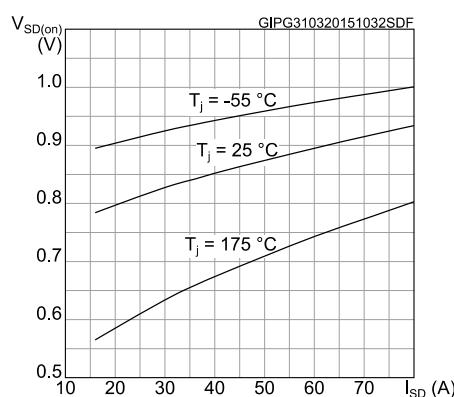


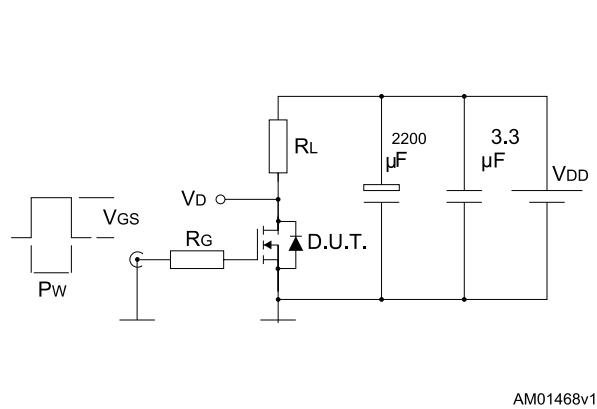
Figure 7: Static drain-source on-resistance



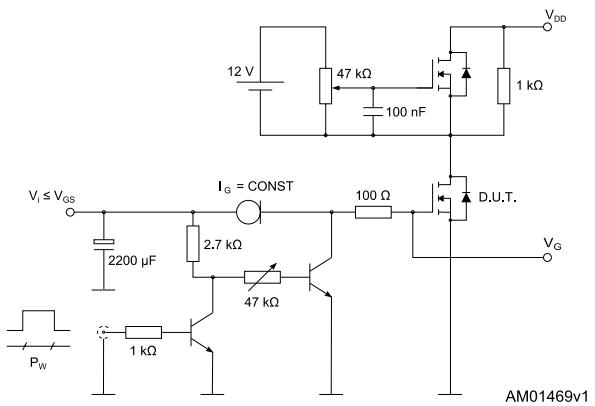
**Figure 8: Capacitance variations****Figure 9: Normalized gate threshold voltage vs temperature****Figure 10: Normalized on-resistance vs temperature****Figure 11: Normalized V(BR)DSS vs temperature****Figure 12: Source-drain diode forward characteristics**

### 3 Test circuits

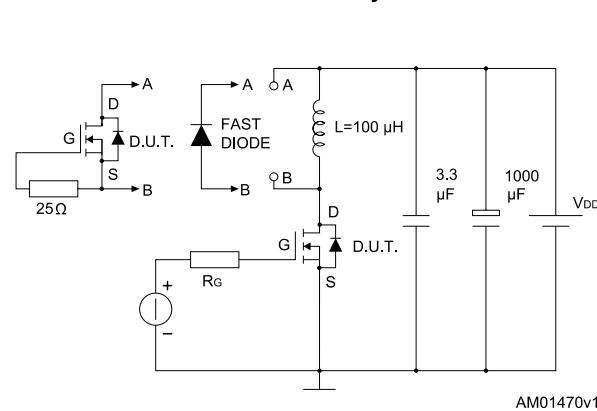
**Figure 13: Switching times test circuit for resistive load**



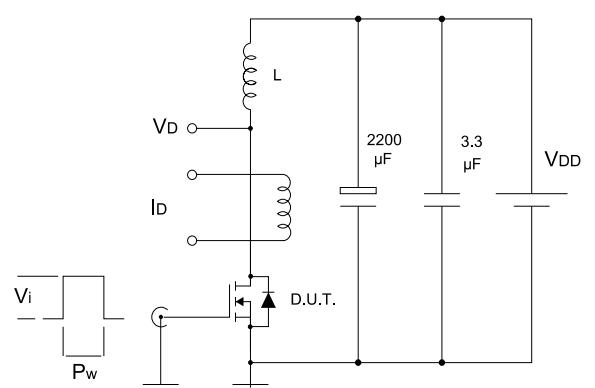
**Figure 14: Gate charge test circuit**



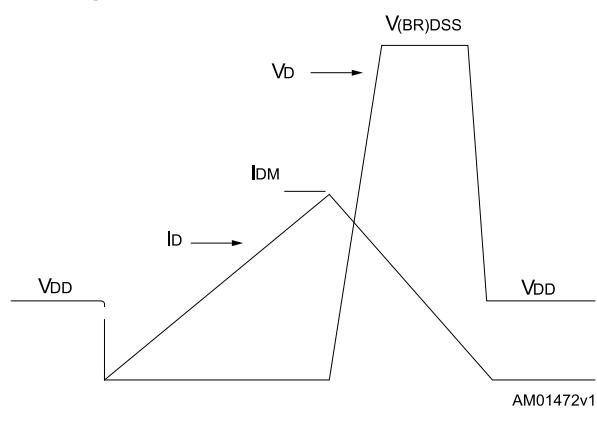
**Figure 15: Test circuit for inductive load switching and diode recovery times**



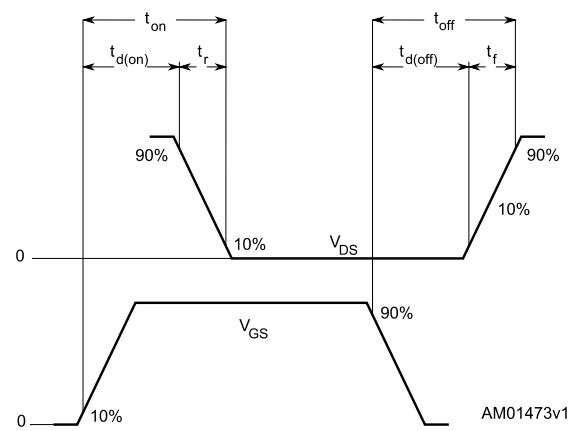
**Figure 16: Unclamped inductive load test circuit**



**Figure 17: Unclamped inductive waveform**



**Figure 18: Switching time waveform**



## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
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## 4.1 H<sup>2</sup>PAK-2 package information

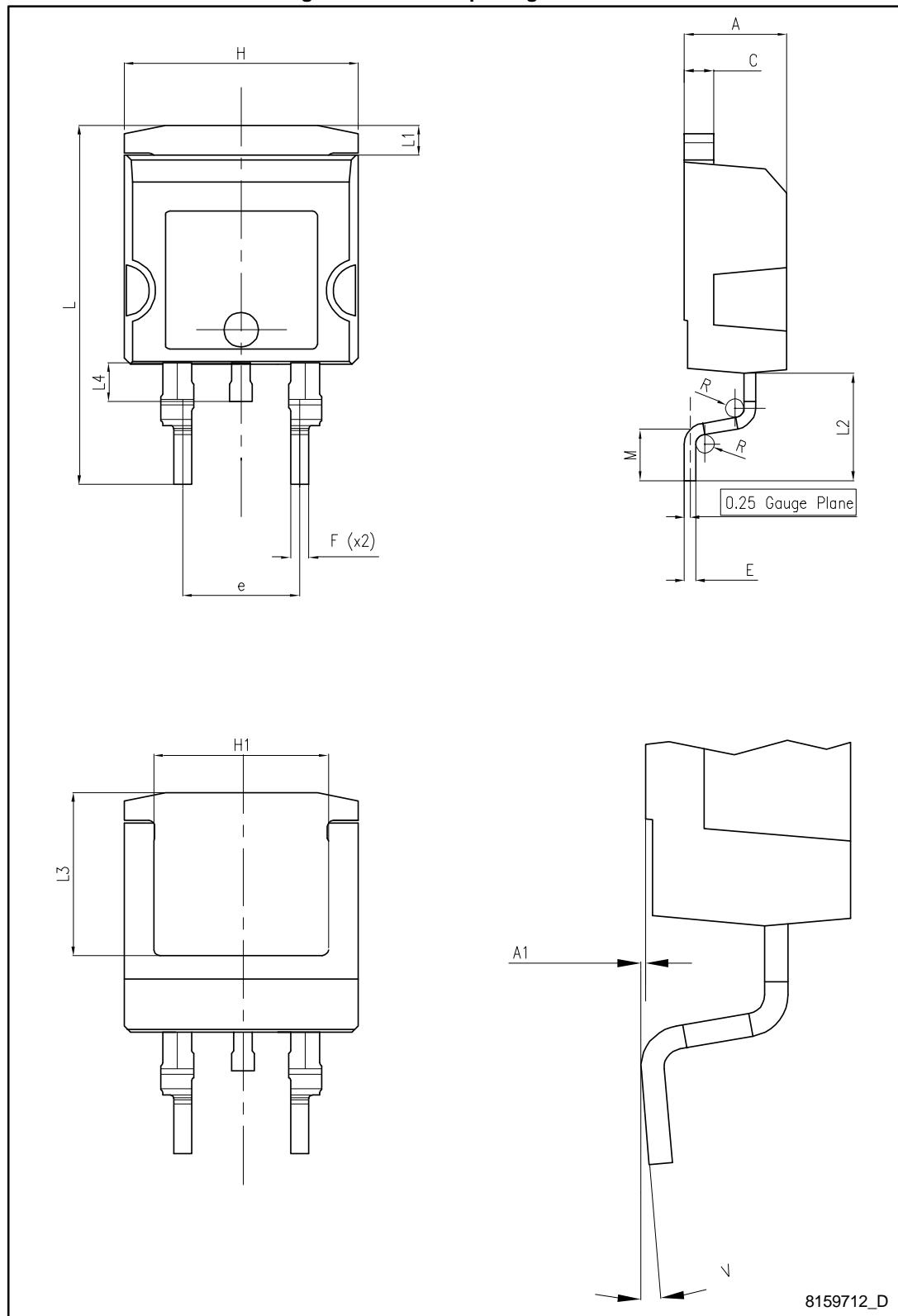
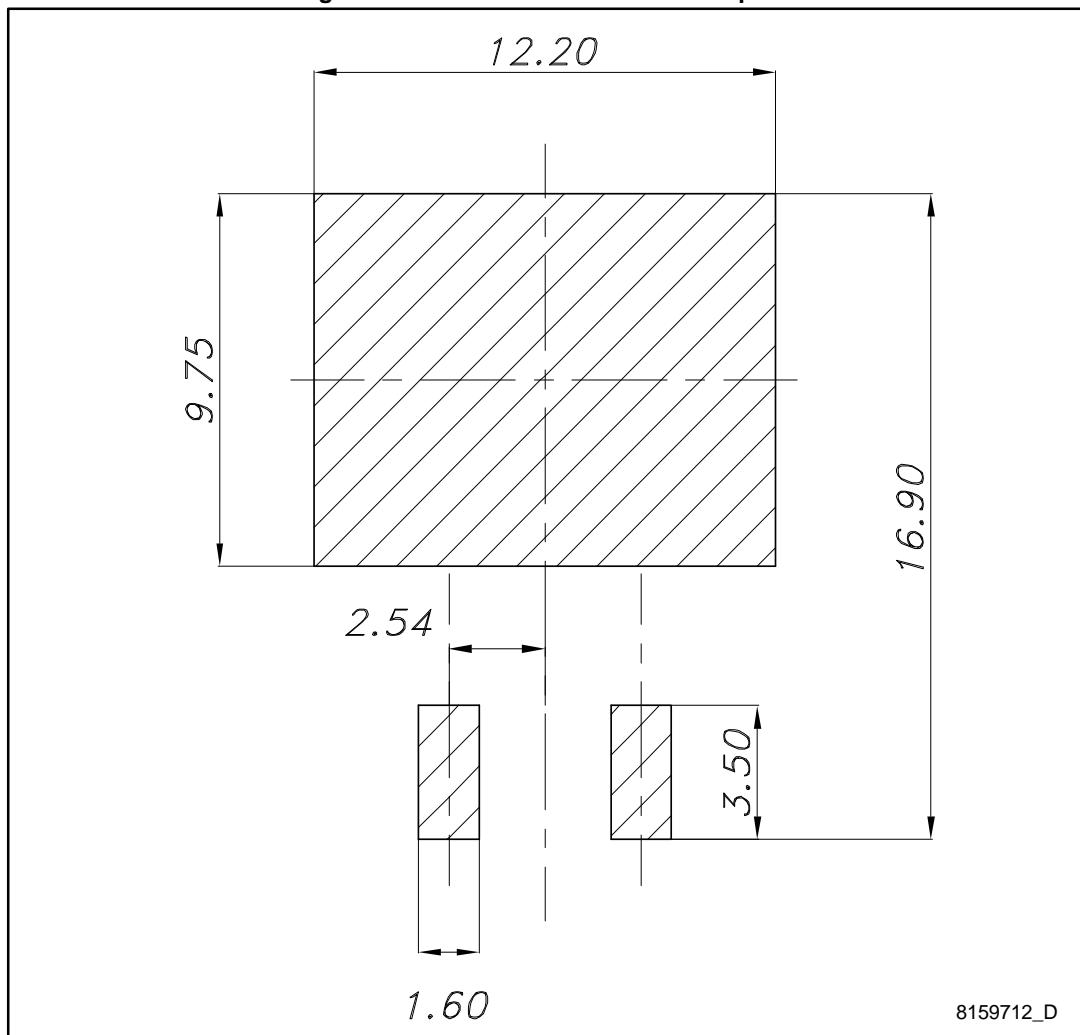
Figure 19: H<sup>2</sup>PAK-2 package outline

Table 8: H<sup>2</sup>PAK-2 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.30		4.80
A1	0.03		0.20
C	1.17		1.37
e	4.98		5.18
E	0.50		0.90
F	0.78		0.85
H	10.00		10.40
H1	7.40		7.80
L	15.30		15.80
L1	1.27		1.40
L2	4.93		5.23
L3	6.85		7.25
L4	1.5		1.7
M	2.6		2.9
R	0.20		0.60
V	0°		8°

Figure 20: H<sup>2</sup>PAK-2 recommended footprint

## 4.2 H<sup>2</sup>PAK-6 package information

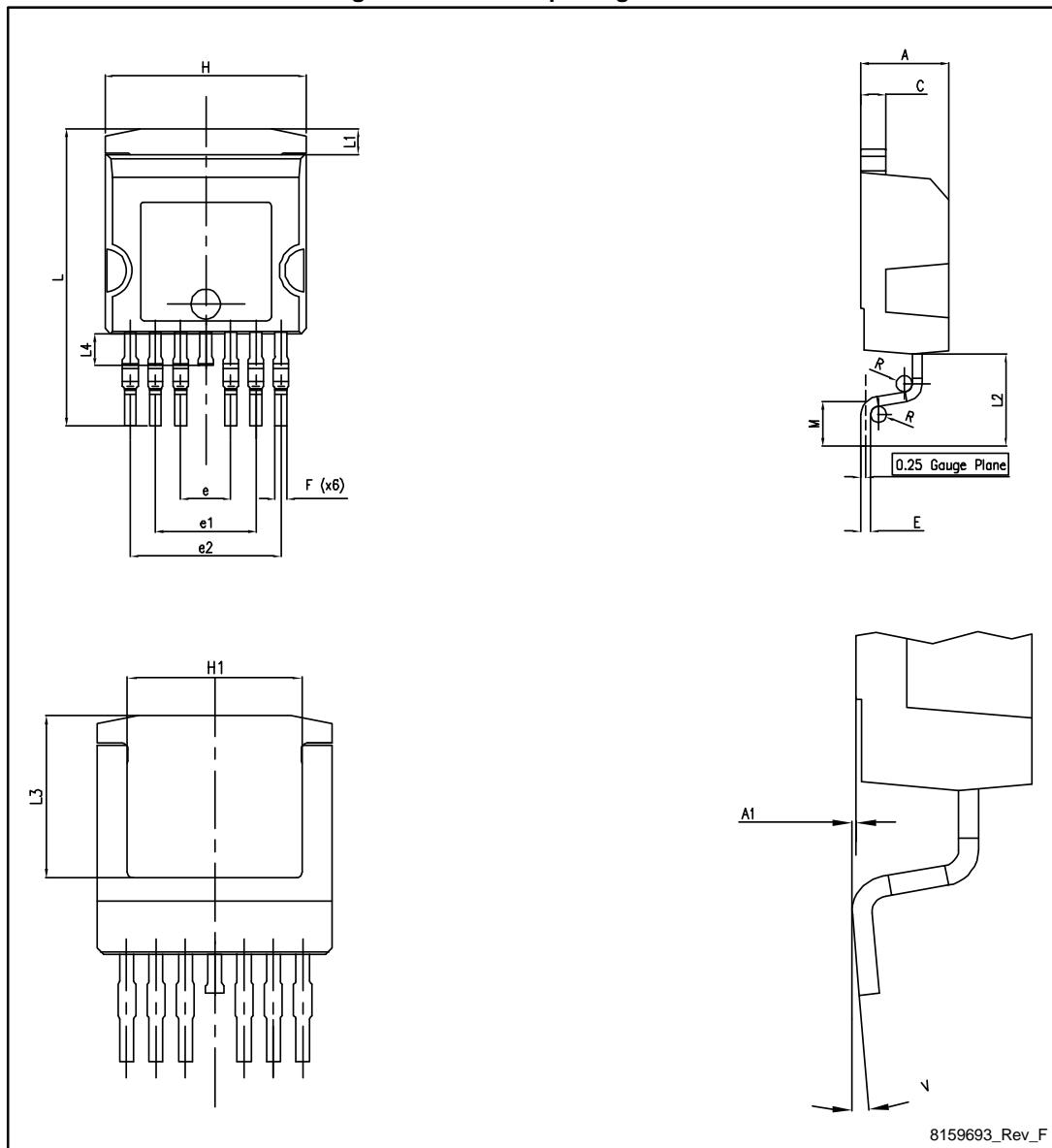
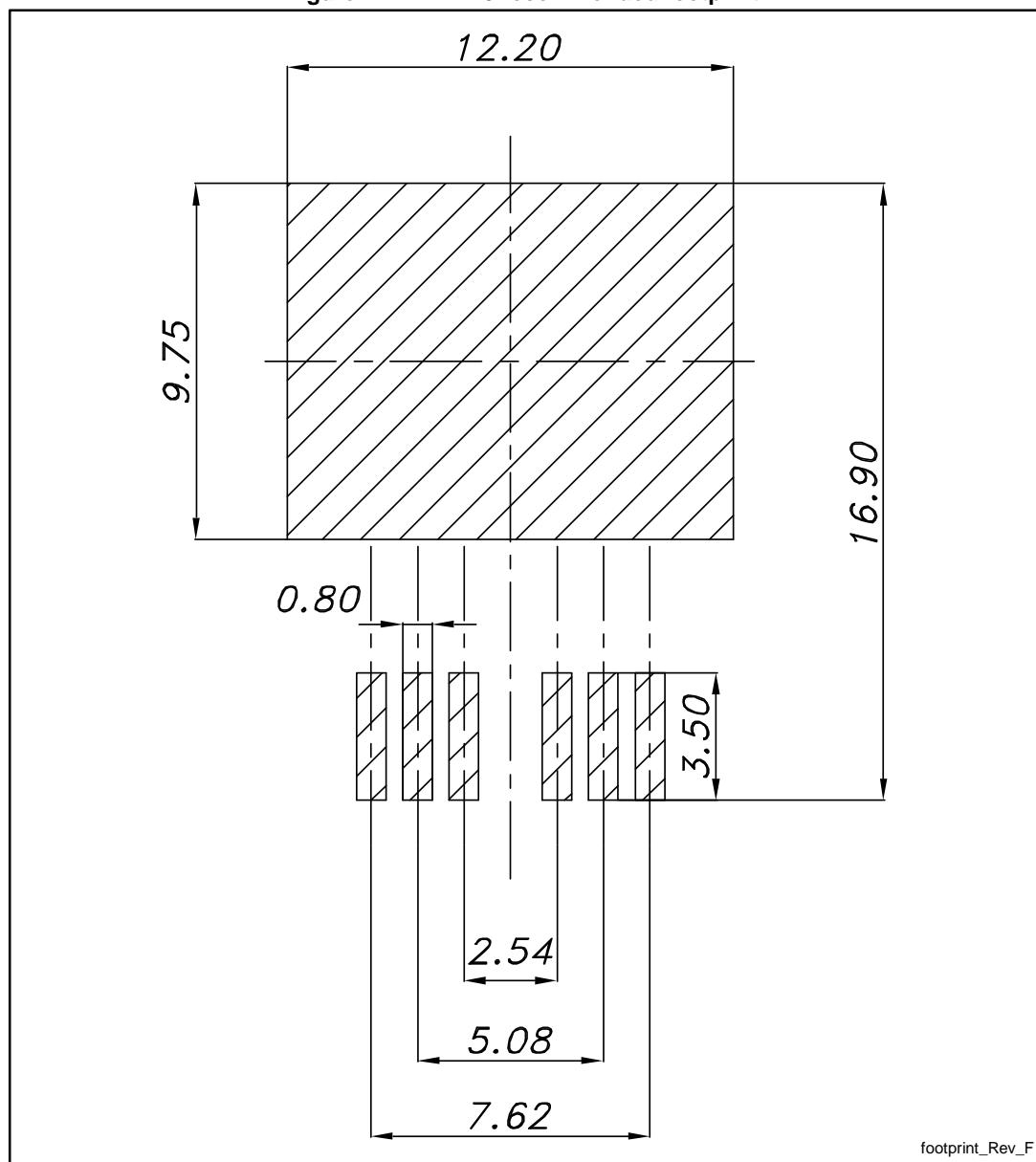
Figure 21: H<sup>2</sup>PAK-6 package outline

Table 9: H<sup>2</sup>PAK-6 package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.30		4.80
A1	0.03		0.20
C	1.17		1.37
e	2.34		2.74
e1	4.88		5.28
e2	7.42		7.82
E	0.45		0.60
F	0.50		0.70
H	10.00		10.40
H1	7.40		7.80
L	14.75		15.25
L1	1.27		1.40
L2	4.35		4.95
L3	6.85		7.25
L4	1.5		1.75
M	1.90		2.50
R	0.20		0.60
V	0°		8°

Figure 22: H<sup>2</sup>PAK-6 recommended footprint

Dimensions are in mm.

### 4.3 H<sup>2</sup>PAK packing information

Figure 23: Tape outline

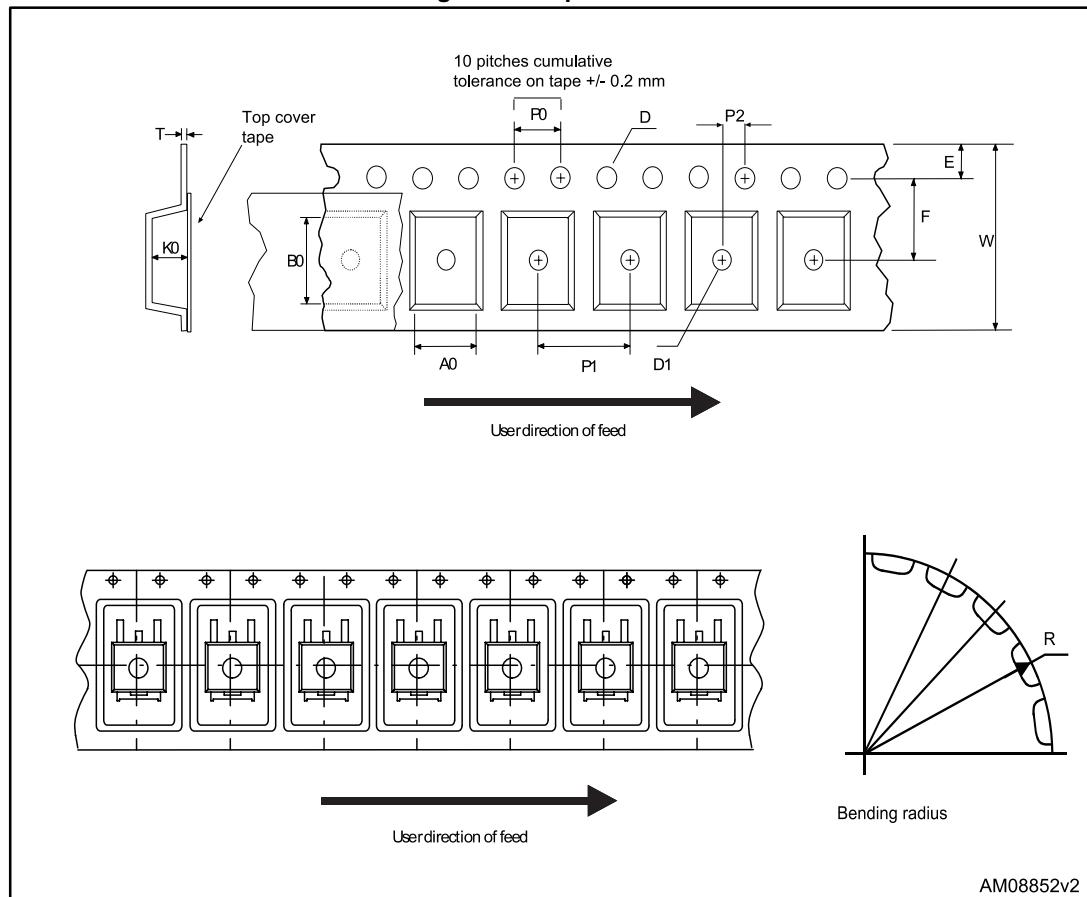


Figure 24: Reel outline

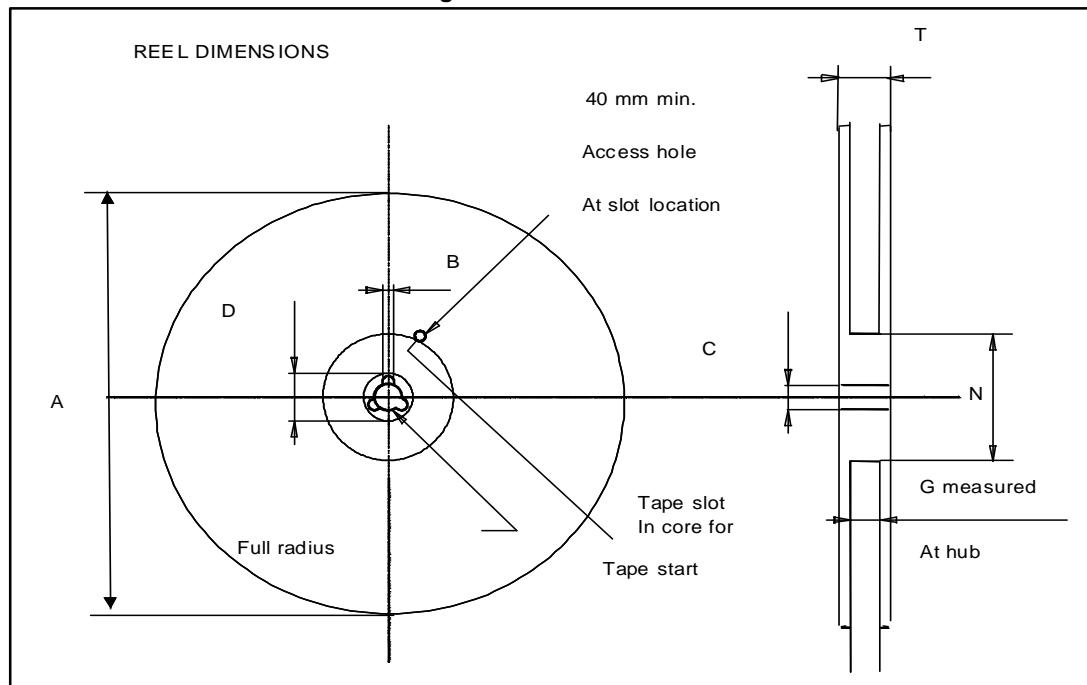


Table 10: Tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base quantity		1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

## 5 Revision history

Table 11: Document revision history

Date	Revision	Changes
02-Aug-2013	1	Initial release.
01-Apr-2015	2	<p>Throughout document:</p> <ul style="list-style-type: none"><li>• minor text changes</li><li>• added H<sup>2</sup>PAK-6 package information.</li><li>• removed TO-220FP and TO-220 package information.</li></ul> <p>In Section 1 Electrical ratings:</p> <ul style="list-style-type: none"><li>• updated Table 2. Absolute maximum ratings</li><li>• updated Table 3. Thermal data</li></ul> <p>In Section 2 Electrical characteristics:</p> <ul style="list-style-type: none"><li>• updated and renamed Table 4. Static (was "On /off states")</li><li>• updated Table 5. Dynamic</li><li>• updated Table 6. Switching times</li><li>• updated Table 7. Source drain diode</li><li>• added Section 2.1 Electrical characteristics (curves)</li></ul>
16-Jul-2015	3	Document status promoted from preliminary to production data.

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